

# IGBT Ignition Predriver with Dynamic Current Regulation

### Description

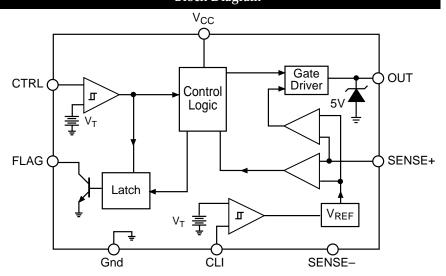
The CS8312 is a bipolar microprocessor interface IC designed to drive an IGBT (or logic level MOSFETs) powering large inductive loads in harsh operating environments. The IC's dynamic current limit function lets the microprocessor adjust the current limit threshold to the real time needs of the system.

CLI, the current limit input, sets the current limit for the IGBT high or low as directed by the system microprocessor. CLI also raises and lowers the threshold on the diagnostic FLAG output signal. The FLAG output signals the microprocessor when the current level approaches current limit on the IGBT. The CTRL input enables the FLAG function.

#### **Absolute Maximum Ratings**

Supply Voltage0.3V to +12	V
Digital Input Currents2m	A
Internal Power Dissipation (T <sub>A</sub> = 25°C)700mV	
Junction Temperature Range40°C to +150°	C
Storage Temperature Range55°C to +165°	C
Lead Temperature Soldering	
Wave Solder(through hole styles only)10 sec. max, 260°C pea	ık
Reflow (SMD styles only)60 sec. max above 183°C, 230°C pea	ιk
Electrostatic Discharge (Human Body Model)2k	V

#### **Block Diagram**

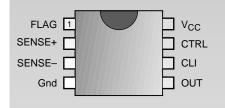


#### **Features**

- $\mu$ P Compatible Inputs
- Adjustable Current Limit
  Thresholds
- **External Sense Resistor**
- Flag Signal to Indicate Output Status

#### **Package Options**

**8L PDIP & SO Narrow** 





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Electrical Characteristics	$7V \le V_{CC} \le 10V$ ; $-40^{\circ}C \le T_{A} \le +125^{\circ}C$ unless otherwise spec			ia voitage≤t	7.0 V ,
PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
General					
Power Supply including Ripple Voltage		7		10	V
Supply Ripple Frequency		10		60	kHz
Differential Ground Frequency	y	10		60	kHz
Quiescent Current, $I_Q$					
Turn On Turn Off	$V_{CTRL} = 5.5V$ $V_{CTRL} = -0.3V$			15 5	mA mA
Supply Voltage Rejection	$V_{CTRL} = 5.5V$	30			dB
Differential Ground Rejection Ratio	$V_{CTRL} = 5.5V$	30			dB
Differential Ground Current Ratio	$V_{CTRL} = -0.3V$ $(V_{SENSE}-V_{Gnd})DC = 1V$ $(V_{SENSE}-V_{Gnd})AC = 0.6V$			3	mA
Unity Gain Bandwidth	$V_{CTRL} = 5.5V$	400			kHz
Turn On Delay	CTRL increasing			30	us
Turn Off Delay	CTRL decreasing			30	us
Control Function					
Control Function Input Voltage Range	$I_{\text{CTRL}} = 2\text{mA}$	-0.3		5.5	V
Input Threshold	I <sub>CTRL</sub> = ZIIIA	-0.3		5.5	V
Turn On	CTRL increasing			3.5	V
Turn Off	CTRL decreasing	1.5			V
Hysteresis		0.4		2.0	V
Voltage	$I_{CTRL} = 10\mu A MAX$			1.1	V
Input Capacitance				50	pF
Current Limit Increase Functi	ion				
Input Voltage Range	$I_{\text{CTRL}} = 2\text{mA}$	-0.3		5.5	V
Input Threshold	-CIRL			0.0	•
Turn On	CLI increasing			3.5	V
Turn Off	CLI decreasing	1.5			V
Hysteresis		0.4		2.0	V
Voltage	$I_{CLI} = 10\mu A \text{ max}$			1.1	V
Input Capacitance				50	pF
Output Stage				- <u> </u>	
I <sub>OUT</sub>				5	mA
Clamp Voltage	$V_{CTRL} = 5.5V; I_{OUT} = 1mA$	4.0		5.5	V
Output Off Voltage	$V_{CTRL} = -0.3V; I_{OUT} = 10 \mu A$ $V_{CTRL} = -0.3V; I_{OUT} = 200 \mu A$			0.5	V V
Flag Function					
Output Low	$V_{CTRL} = 5.5V$ ; $I_{FLAG} = 1.5mA$			0.9	V
Leakage Current	$V_{CTRL} = -0.3V$			10	μΑ
Output Capacitance				50	pF
Turn On (V <sub>SENSE+</sub> - V <sub>SENSE-</sub> )	$V_{CTRL} = 5.5V; V_{CLI} = -0.3V$	210	225	240	mV
	$V_{CTRL} = 5.5V; V_{CLI} = 5.5V$	300		350	mV

## Electrical Characteristics $7V \le V_{CC} \le 10V$ ; $-40^{\circ}C \le T_{A} \le +125^{\circ}C$ ; $-0.2V \le Differential Ground Voltage \le 0.8V$ ; unless otherwise specified.

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
■ Flag Function: continued					
Turn Off Delay	CTRL decreasing			10	us
Turn On Delay				10	us
Disable Time		100		450	us
■ Sense Function					
Input Voltage Range		-0.3		2.5	V
Sense Regulation Voltage	$V_{CTRL} = 5.5V$ ; $V_{CLI} = -0.3V$	270	295	320	mV
	$V_{CTRL} = 5.5V; V_{CLI} = 5.5V$	380	410	440	mV
Input Leakage Current	$V_{CTRL} = 5.5V$			5	μΑ
Propagation Delay	$V_{CTRL} = 5.5V$			20	us

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PACKAGE PIN #	PIN SYMBOL	FUNCTION
8L PDIP & SO		
1	FLAG	Indicates whether current through the IGBT has reached a preset level.
2	SENSE+	Positive input to current comparator.
3	SENSE-	Ground (SENSE-) for current sense resistor.
4	Gnd	Ground connection.
5	OUT	Output voltage to IGBT (MOSFET) gate.
6	CLI	Current limit input increase.
7	CTRL	Control input.
8	$V_{cc}$	Supply voltage.

#### Circuit Description

#### Flag Function (see Application Diagram)

The flag indicates when the voltage across the two sense pins is approaching a current limit level that has been determined by the value of the external sense resistor ( $R_{SENSE}$ ) and the state of the CTRL and CLI pins. If the voltage across the sense pins (SENSE+, SENSE-) is less than the flag turn-on voltage, then the FLAG is off. When the voltage between the sense pins equals the FLAG turn on voltage, the FLAG will latch on until the CTRL pin goes low. FLAG is disabled whenever CTRL is low. Changing the CLI pin from low to high will increase nominal FLAG turn on voltage by approximately 45%.

**Table 1 FLAG Timing Sequence** 

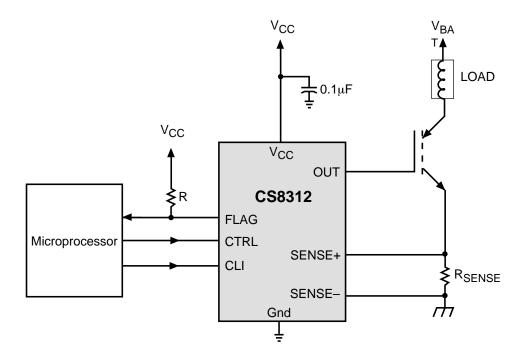
State	CONTROL	SENSE+	FLAG
0	Low	X	OFF
1	High	<b>Below Threshold</b>	OFF
2	High	Above Threshold	ON
3	High	X	ON
0	Low	X	OFF

#### **Output Stage**

The CS8312 output (OUT) saturates and supplies voltage to the IGBT (or MOSFET) gate once the CTRL switches from low to high. As current through the IGBT (MOSFET) increases and the voltage across the sense resistor passes the flag turn on voltage, the FLAG will turn on. If the current through the sense resistor continues to rise and the sense resistor voltage reaches the regulation sense voltage, then the gate voltage will fall to a level that regulates the driver and maintains the regulation sense voltage at the sense resistor.

#### **Current Limit Function**

Changing the CLI pin from a logic low to a logic high increases the FLAG turn on voltage by approximately 45% and the regulation sense voltage by approximately 39% respectively.



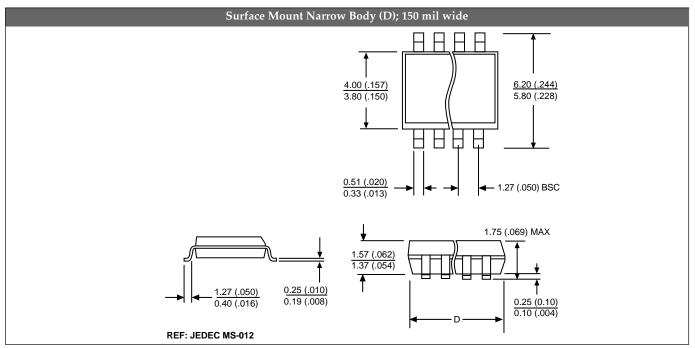
#### **Package Specification**

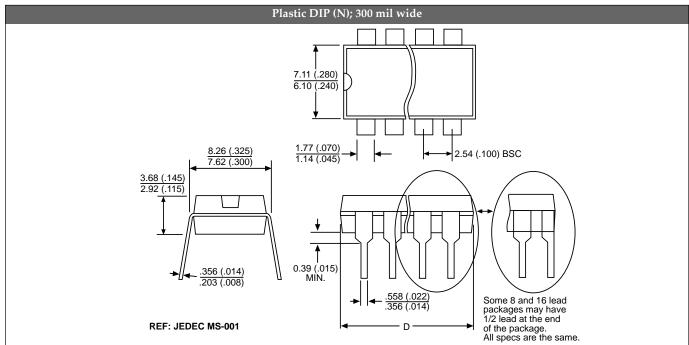
#### PACKAGE DIMENSIONS IN mm (INCHES)

		D		
Lead Count	Met	tric	Eng	glish
	Max	Min	Max	Min
8 Lead SO Narrow	5.00	4.80	.197	.189
8 Lead PDIP	10.16	9.02	.400	.355

#### PACKAGE THERMAL DATA

Therma	1 Data	8L SO	8L PDIP	
$R_{\Theta JC}$	typ	45	52	°C/W
$R_{\Theta JA}$	typ	165	100	°C/W





#### **Ordering Information**

Part Number	Description
CS8312YN8	8L PDIP
CS8312YD8	8L SO Narrow
CS8312YDR8	8L SO Narrow (tape & reel)

Cherry Semiconductor Corporation reserves the right to make changes to the specifications without notice. Please contact Cherry Semiconductor Corporation for the latest available information.